

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-40V	25mΩ@-10V	-16A
	35mΩ@-4.5V	



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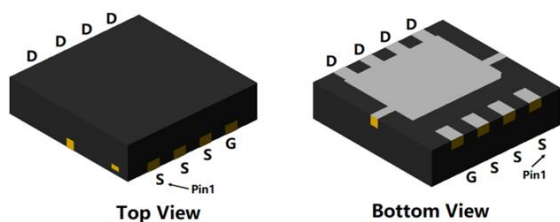
Feature

- Fast switching speed
- Low On-Resistance
- 100% Single Pulse avalanche energy Test

Applications

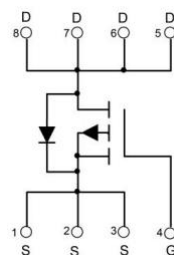
- DC-DC Converters.
- Power Management

Package

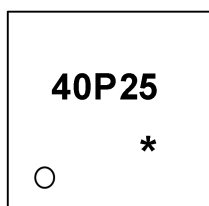


PDFN3X3-8L

Circuit diagram



Marking



40P25
*

:Device Code
:Month Code

Order Information

Device	Package	Unit/Tape
SP40P25NJ	PDFN3X3-8L	5000

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	-40	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current (Tc=25°C)	I_D	-16	A
Continuous Drain Current (Tc=100°C)	I_D	-11	A
Pulse Drain Current Tested	I_{DM}	-64	A
Single Pulse Avalanche Energy ¹	E_{AS}	60	mJ
Power Dissipation (Tc=25°C)	P_D	28	W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	4.5	°C/W
Storage Temperature Range	T_{STG}	-55 to 150	°C
Operating Junction Temperature Range	T_J	-55 to 150	°C

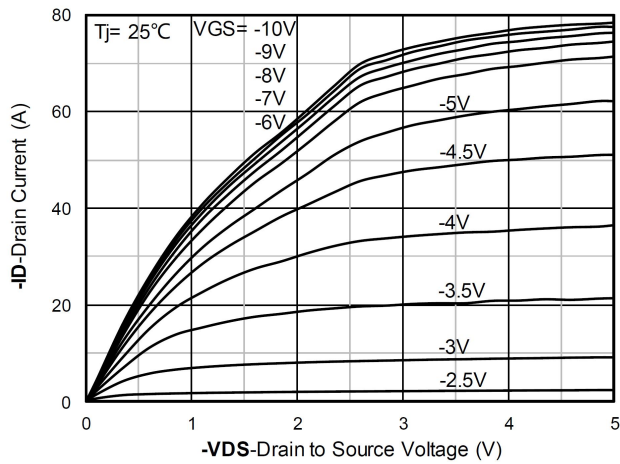
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=-250uA	-40	-	-	V
Drain-Source Leakage Current	IDSS	VDS=-32V , VGS=0V , TJ=25℃	-	-	-1	uA
Gate-Source Leakage Current	IGSS	VGS=±20V , VDS=0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	VGS=VDS , ID =-250uA	-1.2	-1.5	-2.2	V
Static Drain-Source On-Resistance	RDS(ON)	VGS=-10V , ID=-5A	-	25	35	mΩ
		VGS=-4.5V , ID=-4A	-	35	50	
Dynamic characteristics						
Input Capacitance	Ciss	VDS=-20V , VGS=0V , f=1MHz	-	1415	-	pF
Output Capacitance	Coss		-	134	-	
Reverse Transfer Capacitance	Crss		-	102	-	
Total Gate Charge	Qg	VDS=-15V , VGS=-10V , ID=-10A	-	23.5	-	nC
Gate-Source Charge	Qgs		-	3.5	-	
Gate-Drain Charge	Qgd		-	3.3	-	
Switching Characteristics						
Turn-On Delay Time	Td(on)	VDD=-15V VGS=-10V , RG=3Ω, ID=-6A	-	11	-	nS
Rise Time	Tr		-	15.7	-	
Turn-Off Delay Time	Td(off)		-	35	-	
Fall Time	Tf		-	5.5	-	
Diode Characteristics						
Diode Forward Voltage	VSD	VGS=0V , IS=-1A , TJ=25℃	-	-	-1.2	V
Maximum Body-Diode Continuous Current	IS		-	-	-16	A
Reverse recover time	Trr	IS=-15A, di/dt=-100A/us, Tj=25℃	-	28	-	nS
Reverse recovery charge	Qrr		-	36	-	nC

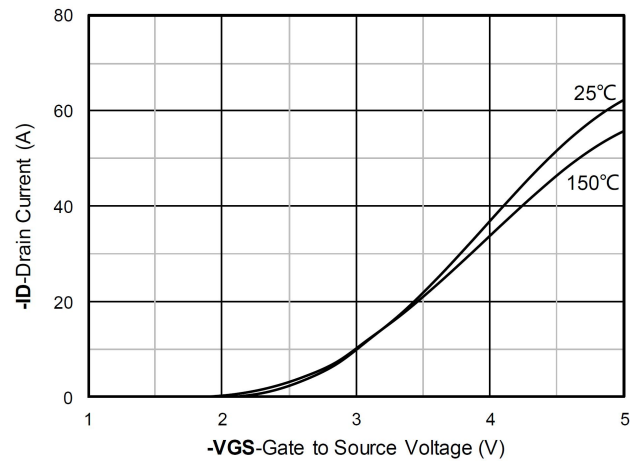
Note:

- The EAS test condition is $V_{DD}=-20V, V_G=-10V, L=1mH, R_g=25\Omega$

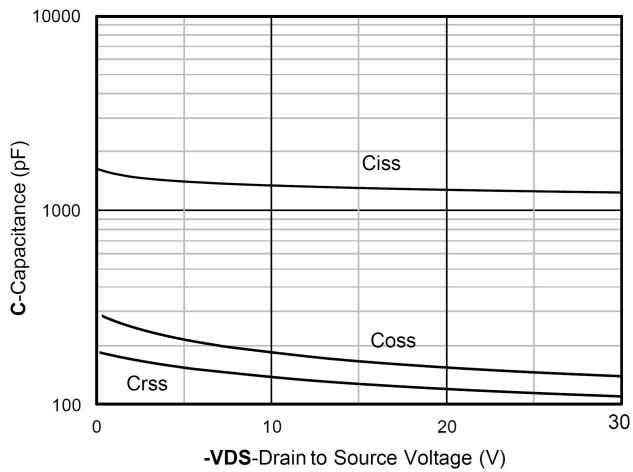
Typical Characteristics



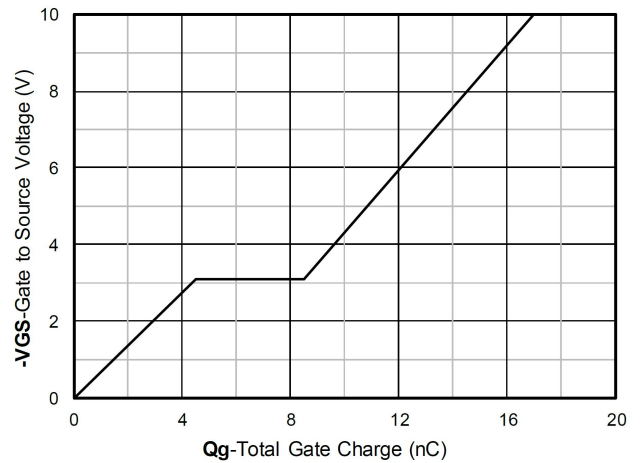
Output Characteristics



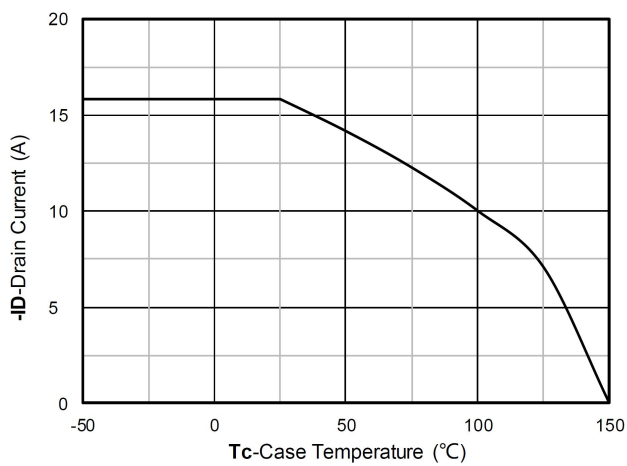
Transfer Characteristics



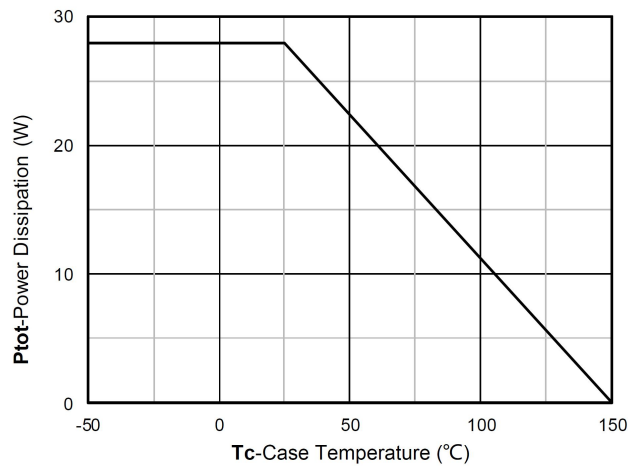
Capacitance Characteristics



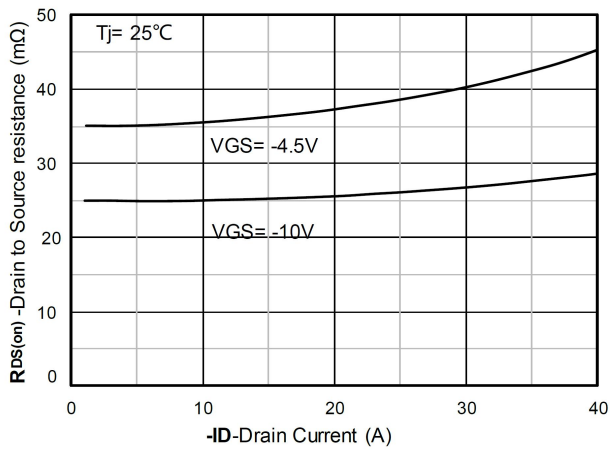
Gate Charge



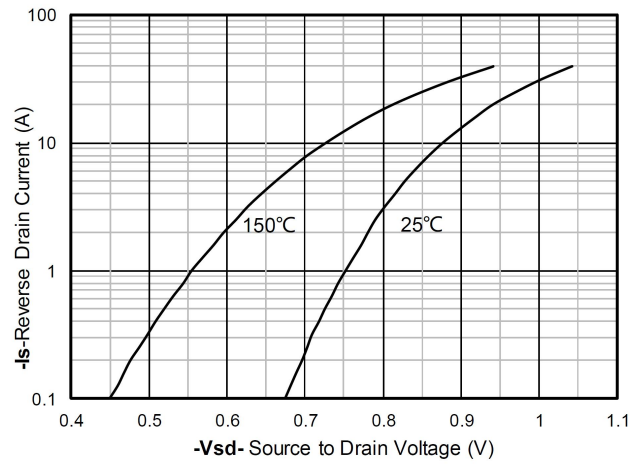
Current dissipation



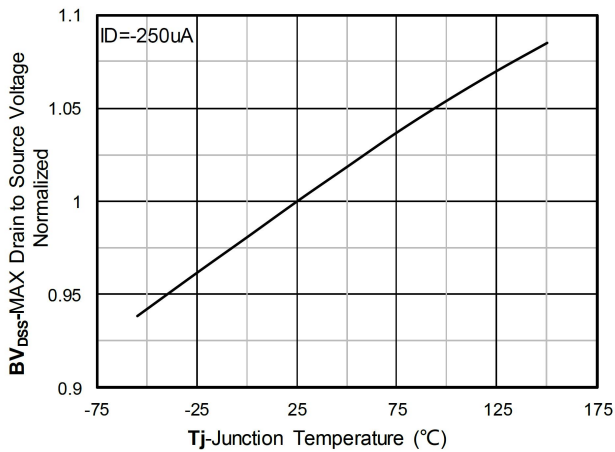
Power dissipation



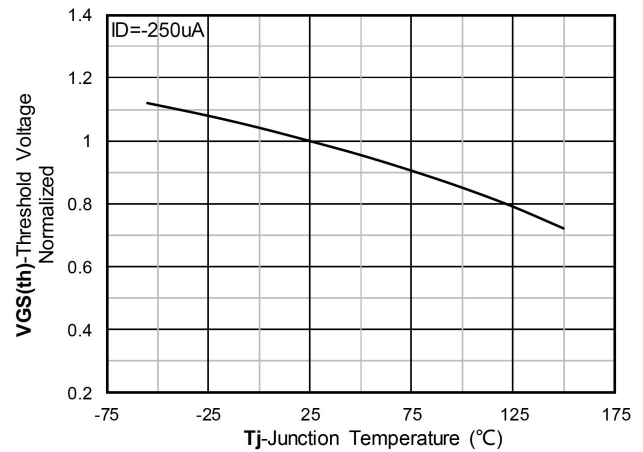
RDS(on) VS Drain Current



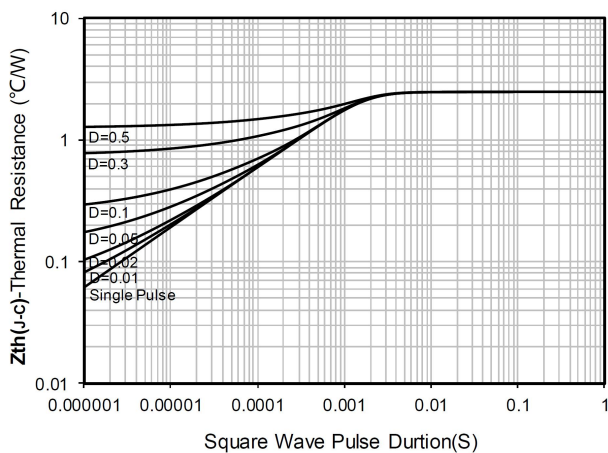
Forward characteristics of reverse diode



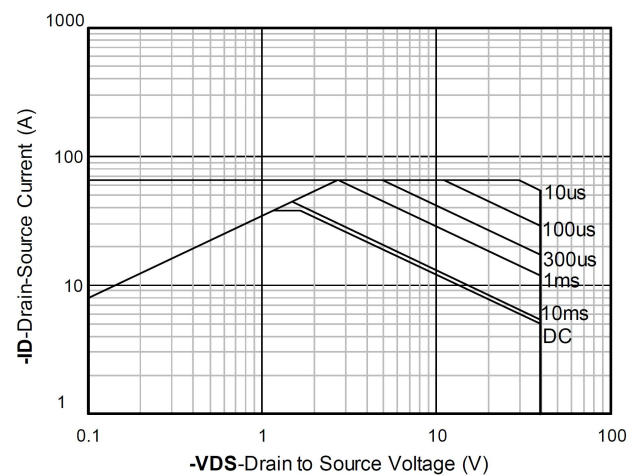
Normalized breakdown voltage



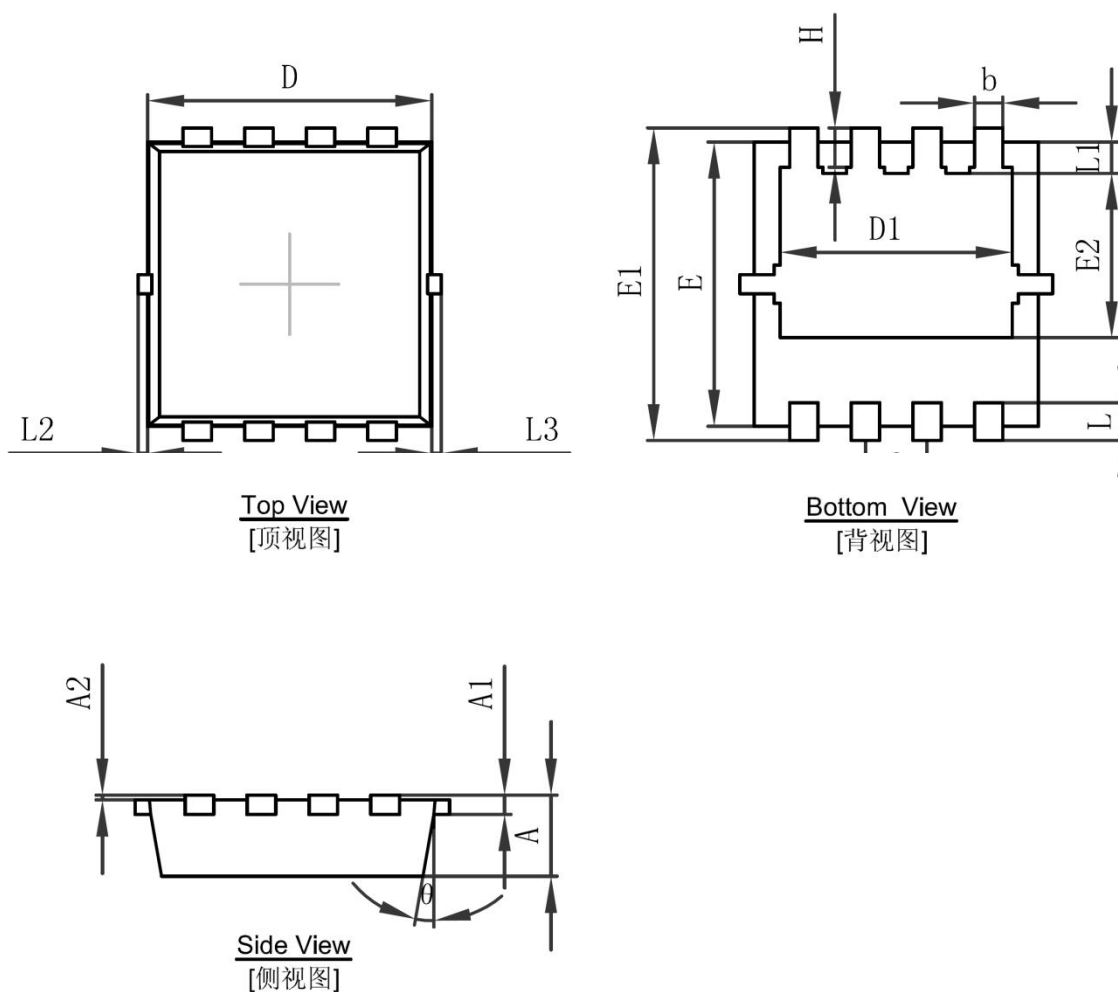
Normalized Threshold voltage



Maximum Transient Thermal Impedance



Safe Operation Area

PDFN3X3-8L Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.650	0.850	0.026	0.033
A1	0.152 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	2.900	3.100	0.114	0.122
D1	2.300	2.600	0.091	0.102
E	2.900	3.100	0.114	0.122
E1	3.150	3.450	0.124	0.136
E2	1.535	1.935	0.060	0.076
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0~0.100		0~0.004	
L3	0~0.100		0~0.004	
H	0.315	0.515	0.012	0.020
θ	9°	13°	9°	13°

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